

LVDS SD-B2D00 Series

Rev. J

Description

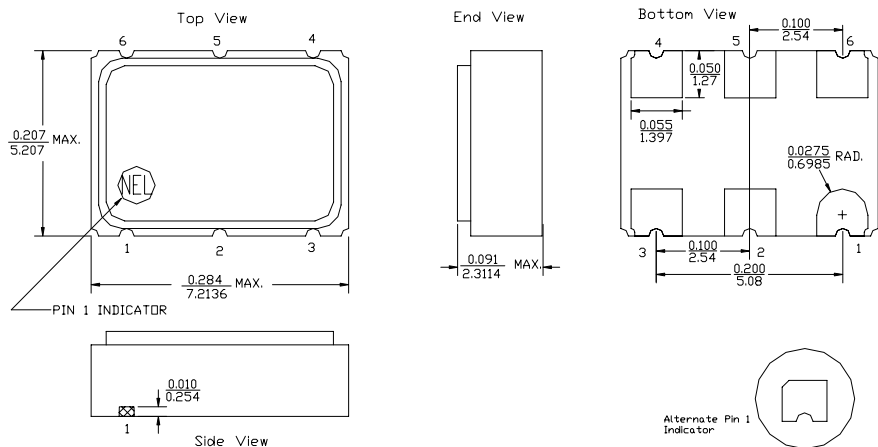
The **SD-B2D00 Series** of quartz crystal oscillators provide LVDS compatible signals in a ceramic SMD package. Systems designers may now specify space-saving, cost-effective packaged LVDS oscillators to meet their timing requirements.

Features

- Wide frequency range—80.0MHz to 312.5MHz
- User specified tolerance available
- Space-saving alternative to discrete component oscillators
- High shock resistance, to 1000g
- 2.5 volt operation (other voltages available upon request)
- Metal lid electrically connected to ground to reduce EMI
- Enable/Disable
- LVDS output on pin 4, complement on Pin 5
- Low Jitter - Wavecrest jitter characterization available
- High Reliability - NEL HALT/HASS qualified for crystal oscillator start-up conditions
- Overtone technology
- High Q Crystal actively tuned oscillator circuit
- Power supply decoupling internal
- No internal PLL avoids cascading PLL problems
- High frequencies due to proprietary design
- Gold plated pads
- RoHS Compliant, Lead Free Construction

Electrical Connection

Pin	Connection
1	Enable/Disable
2	N.C.
3	Ground
4	Output
5	Output Complement
6	V _{CC}



ALL DIMENSIONS: $\frac{\text{IN}}{\text{mm}}$
All tolerances are ± 0.005 inches (± 0.127 mm) unless otherwise specified.

SD-B2D00 Series Continued
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Operating Conditions and Output Characteristics

Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max
Frequency	----	----	80.0MHz	----	312.5MHz
Duty Cycle ⁽²⁾	----	@ V _O /2	45/55%	----	55/45%
Logic 0 ⁽²⁾	V _{OL}	----	0.80V	----	1.10V
Logic 1 ⁽²⁾	V _{OH}	----	1.25V	----	1.55V
Differential Voltage ⁽²⁾	V _{OD}	----	250 mV	----	450 mV
Disable Voltage	----	V _{EE} =0V	----	----	0.8V
Enable Voltage ⁽⁵⁾	----	V _{EE} =0V	2.0V	----	----
Rise & Fall Time ⁽²⁾	tr,tf	20-80%V _O	----	0.8 ns	1.0 ns
Tpd ⁽⁴⁾	----	----	-0.5 ns	----	+0.5 ns
Jitter, RMS ⁽³⁾	----	----	----	----	3 psec
Frequency Stability ⁽¹⁾	dF/F	Overall conditions including: voltage, calibration, temp., 10 yr aging, shock, vibration	-100ppm	----	+100ppm

General Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max
Supply Voltage	V _{CC}	----	2.375V	2.5V	2.625V
Supply Current	I _{CC}	----	0.0 mA	----	80 mA
Output current	I _O	Continuous Output Current	0.0 mA	----	±50.0 mA
Operating temperature	T _A	----	0°C	----	70°C
Storage temperature	T _S	----	-55°C	----	125°C
Power Dissipation	P _D	----	----	----	210 mW
Solder temperature	T _L	4 minutes	----	----	253°C
Load	100 ohms across differential outputs		----	----	----
Start-up time	t _s	----	----	2 ms	10 ms

Environmental and Mechanical Characteristics

Mechanical Shock	Per MIL-STD-202, Method 213, Condition E
Thermal Shock	Per MIL-STD-883, Method 1011, Condition A
Vibration	0.060" double amplitude 10 Hz to 55 Hz, 35g's 55Hz to 2000 Hz
Hermetic Seal	Leak rate less than 1 x 10 ⁻⁸ atm.cc/sec of helium

Footnotes:

- 1) Standard frequency stability (±20,±25,±50ppm & others available)
- 2) With Load of 100 ohms across differential outputs.
- 3) Jitter performance is frequency dependent. Please contact factory for full Wavecrest characterization.
RMS jitter bandwidth of 12kHz to 20Mhz.
- 4) Tpd is phase shift between the falling edge of pin 4 and the rising edge of pin 5.
- 5) Open to enable pin also enables the output

